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Docket	NO.	

DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

SINGLE ELECTRON	MEMORY	DEVICE CO	MPRISING	OUANTUM	DOTS	BETWEEN	GATE
ELECTRODE AND	SINGLE	ELECTRON	STORAGE	ELEMENT	AND	METHOD	FOR
MANUFACTURING 1	THE SAME					-	

MANUFACTURING THE					
the specification of which is	attache	ed hereto unless the follow	wing box is	s checked:	
was filed on Number	and v		oplication Nun	nber or PCT International (if applicable)	
I hereby state that I have reviewe amended by any amendment referre	d and u	inderstand the contents of the			ing the claims, as
I acknowledge the duty to disclose i Federal Regulations § 1.56.	nformat	ion which is known by me to t	be material to	patentability as defined in	Title 37, Code of
I hereby claim foreign priority bene- patent or inventor's certificate, or the United States, listed below and International application having a fil	fits unde § 365(a have al ing date	er Title 35, United States Code i) of any PCT International application of the applicati	e, § 119(a)-(d) plication whic in application on which prio	or § 365(b) of any foreign ch designated at least one for patent or inventor's cority is claimed:	n application(s) for country other than certificate, or PCT
PRIOR FOREIGN APPLIC	CATIO	ON(S)			
NUMBER		COUNTRY	DA	Y/MONTH/YEAR FILED	PRIORITY CLAIMED
2001-25569		Rep. of Korea		10/May/2001	Yes
I hereby claim the benefit under Title 2	25 Unit	-d States Code S 110(a) of any II	Triand States an	A	13 -1
			nited States pr		d below.
APPLICA	TION NO	D.		FILING DATE	
I hereby claim the benefit under Title International application designating the is not disclosed in the prior United States Code, § 112, I acknowledge to 37, Code of Federal Regulations § International filing date of this applications.	ites or P	'CT International application in the	he manner prov	vided by the first paragraph	of Title 35, United
APPLICATION SERIAL NO.		FILING DATE		STATUS: PATENTEL ABANDON	
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Docket No.

I hereby appoint as my attorneys, with full parts of substitution and revocation, to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: Eugene M. Lee, Reg. No. 32,039; Richard A. Steba, Reg. No. 43,162.

Address all correspondence to Eugene M. Lee; Thee & Sterba, P.C. 1101 Wilson Boulevard, Suite 1200, Arlington, Virginia 22209. Address all telephone communications to Eugene M. Lee at (703) 525-0978.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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